Benjamin A. D. Williamson MSci, PhD

Email: benjamin.williamson@ntnu.no (Previous Email: benjamin.williamson.10@ucl.ac.uk)

Employment

Norwegian University of Science and Technology (NTNU) (2019 - Present)

Postdoctoral Researcher in Computational Materials Design

Functional Materials and Materials Chemistry Research Group (FACET)

Advisor: Prof. Sverre M. Selbach

University College London (2018 - 2019)

Postdoctoral Research Associate in Computational Materials Design

Scanlon Materials Theory Group Advisor: Prof. David O. Scanlon

Education

University College London (2014 - 2018)

PhD in Computational Inorganic Materials Chemistry

Thesis title: Understanding the Electronic and Thermodynamic Properties of Wide Band Gap Materials

Supervisor: Prof. David O. Scanlon; Secondary Supervisor: Prof. Claire J. Carmalt

University College London (2010 - 2014)

MSci in Chemistry - 1st Class Honours

MSci dissertation title: Computational Design of Next-Generation p-Type Semiconductors

Supervisor: Prof. David O. Scanlon

BSc dissertation title: Z-Schemes for Photocatalytic Water Splitting

Supervisor: Prof. Furio Cora

The King's School, Rochester (2005 - 2010)

A-levels: Chemistry (A), Maths (B), Music: (B), Art (A)

9 GCSEs: Grade A*- B

Music Scholar, Academic Scholar and Prefect

Westminster Abbey Choir School (2000 - 2005)

Publications

1. Dispelling the Myth of Passivated Codoping in TiO₂

B.A.D. Williamson, J. Buckeridge, N.P. Chadwick, S. Sathasivam, C.J. Carmalt, I.P. Parkin and D.O. Scanlon; *Chemistry of Materials*, 31 (7), 2577-2589 (2019)

DOI: 10.1021/acs.chemmater.9b00257

2. Computationally Driven Discovery of Layered Quinary Oxychalcogendides: Potential p-Type Transparent Conductors?

B.A.D. Williamson, G.J. Limburn, G. Hyett and D.O. Scanlon; *ChemRxiv* (2018) DOI: chemrxiv.7078205

3. Origin of High-Efficiency Photoelectrochemical Water Splitting on Hematite/Functional Nanohybrid Metal Oxide Overlayer Photoanode after a Low Temperature Inert Gas Annealing Treatment

S. Ho-Kimura, **B.A.D. Williamson**, S. Sathasivam, S.J.A. Moniz, G. He, W. Luo, D.O. Scanlon, J. Tang, I.P. Parkin; *ACS Omega*, 4 (1), 1449-1459 (2019)

DOI: 10.1021/acsomega.8b02444

4. Phosphorus Doped SnO₂ Thin Films for Transparent Conducting Oxide Applications: Synthesis, Optoelectronic Properties and Computational Models

M.J. Powell, **B.A.D. Williamson**, S-Y. Baek, J. Manzi, D. Potter, D.O. Scanlon and C.J. Carmalt; *Chemical Science*, 9 (41), 7968-7980 (2018)

DOI: 10.1039/C8SC02152J

5. Enhanced Electrical Properties of Antimony Doped Tin Oxide Thin Films Deposited via Aerosol Assisted Chemical Vapour Deposition

S. Ponja, **B.A.D. Williamson**, S. Sathasivam, D.O. Scanlon, I.P. Parkin, C.J. Carmalt; *Journal of Materials Chemistry C*, 6, 7257-7266 (2018)

DOI: 10.1039/C8TC01929K

6. A Novel Laboratory-based Hard X-ray Photoelectron Spectroscopy System

A. Regoutz, M. Mascheck, T. Wiell, S.K. Eriksson, C. Liljenberg, K. Tetzner, **B.A.D. Williamson**, D. O. Scanlon and P. Palmgren; *Review of Scientific Instruments*, 89 (7), 073105 (2018)

DOI: 10.1063/1.5039829

7. Chemical Vapor Deposition of Photocatalytically Active Pure Brookite TiO₂ Thin Films

A.M. Alotaibi, S. Sathasivam, **B.A.D. Williamson**, A. Kafizas, C. Sotelo-Vazquez, A. Taylor, D.O. Scanlon, and I.P. Parkin; *Chem. Mater.*, 30 (4), 1353-1361 (2018)

DOI: 10.1021/acs.chemmater.7b04944

8. A Deeper Understanding of Interstitial Boron-Doped Anatase Thin Films as A Multifunctional Layer Through Theory and Experiment

M. Quesada-Gonzalez, **B.A.D. Williamson**, C. Sotelo-Vazquez, A. Kafizas, N.D. Boscher, R. Quesada-Cabrera, D.O. Scanlon, C.J. Carmalt, I.P. Parkin; *J. Phys. Chem. C*, 122 (1), 714-726 (2018) DOI: 10.1021/acs.jpcc.7b11142

9. Self-Compensation in Transparent Conducting F-Doped SnO₂

J.E.N. Swallow, **B.A.D. Williamson**, T.J. Whittles, M. Birkett, T.J. Featherstone, N. Peng, A. Abbott, M. Farnworth, K.J. Cheetham, P. Warren, D.O. Scanlon, V.R. Dhanak, T.D.Veal; *Adv. Funct. Mater.*, 1701900 (2017)

DOI: 10.1002/adfm.201701900

10. Chemical Vapor Deposition Synthesis and Optical Properties of Nb₂O₅ Thin Films with Hybrid Functional Theoretical Insight into Band Structure and Band Gaps

S. Sathasivam, **B.A.D. Williamson**, S.A. Al Thabaiti, A.Y. Obaid, S.N. Basahel, M. Mokhtar, D.O.Scanlon, C.J. Carmalt, I.P.Parkin; *ACS Appl. Mater. Interfaces*, 9 (21), 18031-18038 (2017)

DOI: 10.1021/acsami.7b00907

11. Computational and Experimental Study of Ta₂O₅ Thin Films

S. Sathasivam, **B.A.D. Williamson**, A. Kafizas, S.A. Althabaiti, A.Y. Obaid, S.N. Basahel, D.O. Scanlon, C.J. Carmalt, I.P Parkin; *J. Phys. Chem. C*, 121 (1), 202-210 (2017)

DOI: 10.1021/acs.jpcc.6b11073

12. Transparent Conducting n-type ZnO:Sc – Synthesis, Optoelectronic Properties and Theoretical Insight S.C. Dixon, S. Sathasivam, **B.A.D. Williamson**, D.O. Scanlon, C.J. Carmalt, I.P. Parkin; *J. Mater. Chem. C*, 5, 7585-7597 (2017)

DOI: 10.1039/C7TC02389H

13. Engineering Valence Band Dispersion for High Mobility p-Type Semiconductors

B.A.D. Williamson, J. Buckeridge, J. Brown, S. Ansbro, R.G. Palgrave, D.O. Scanlon; *Chem. Mater.*, 29 (6), 2402-2413 (2017)

DOI: 10.1021/acs.chemmater.6b03306

14. *A Single-Source Precursor Approach to Solution Processed Indium Arsenide Thin Films*P. Marchand, S. Sathasivam, **B.A.D. Williamson**, D. Pugh, S.M. Bawaked, S.N. Basahel, A.Y. Obaid, D.O.

Conference Presentations

- 1. Contributed: B.A.D Williamson: *Dispelling the Myth of Passivated Codoping in TiO*₂, MRS Fall Meeting; Boston US, 2018 Oral
- 2. Contributed: B.A.D.Williamson: Computationally Aided Discovery of Layered Quinary Oxychalcogenide p-type Transparent Conductors, MRS Fall Meeting; Boston US, 2018 Poster Winner of the ICDD prize for materials characterisation
- 3. Contributed: B.A.D Williamson: *Doubled Conductivity in Transparent Conducting In*₂*O*₃ *Through Novel Dopant Design*, MMM Hub; Thomas Young Centre, London, UK, 2018 Poster
- 4. Invited: B.A.D Williamson: *Doubled Conductivity in Transparent Conducting In*₂*O*₃ *Through Novel Dopant Design*, MCC 3rd Conference, Lincoln UK, 2018 Oral
- Contributed: B.A.D Williamson: Doubled Conductivity in Transparent Conducting In₂O₃ Through Novel Dopant Design, Gordon Research Conference; Defects In Semiconductors, Colby-Sawyer College, New Hampshire, US, 2018 – Poster
- 6. Invited: B.A.D Williamson: *Beyond Conventional Doping in SnO*₂, Thomas Young Centre, London UK, 2017 Oral
- 7. Contributed: B.A.D Williamson: *Beyond Conventional Doping in SnO*₂, E-MRS; Spring Meeting, Strasbourg France, 2017 Poster
- 8. Contributed: B.A.D Williamson: *Engineering Valence Band Dispersion For High-Mobility p-type Semiconductors*, E-MRS; Spring Meeting, Strasbourg France, 2017 Oral
- 9. Contributed: B.A.D Williamson: *Engineering Valence Band Dispersion For High-Mobility p-type Semiconductors*, MRS Fall Meeting; Boston US, 2016 Poster
- 10. Contributed: B.A.D Williamson: *Engineering Valence Band Dispersion For High-Mobility p-type Semiconductors*, SSCG Christmas Meeting; Canterbury UK, 2015 Poster

Teaching

2014 - 2019: Supervised final year MSci research projects at UCL

2014 - 2019: Demonstrated in 1st year undergraduate workshops

2018 - 2019: Tutor in 1st year undergraduate inorganic chemistry course at UCL

Other Skills and Interests

Considerable experience in the Unix command line as well as in Bash and Python.

Experienced use with the ab-initio codes: VASP and Questaal.

Proficient experience in using the LTFX typesetting system as well as with the Microsoft Office suite.

Active committee member of the University of London Chamber Choir (2010 - present)

Keen interests in cycling, hill walking, classical music, literature and technology.

References

Prof. David O. Scanlon University College London London WCIH 0AJ Tel: (+44) 7943584620

Email: d.scanlon@ucl.ac.uk

Prof. Timothy D. Veal University of Liverpool Liverpool L69 7ZX Tel: (+44) 1517943872 Email: t.veal@liverpool.ac.uk